## NSN 5961-01-080-2058

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-080-2058 **Inclosure Material:** Metal **Overall Length:** 0.050 inches **Overall Diameter:** Between 0.009 inches and 0.011 inches **Internal Configuration:** Junction contact **Internal Junction Configuration:** Npn **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 20.0 collector to base voltage/static/emitter open and 15.0 collector to emitter voltage/static/base open and 1.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 01341-+2725 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**